



Express Mail Label No. EV 570 994 608 US

PATENT APPLICATION

Docket No. 15313.1

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:)
)
	Hsiang-Lan Lung)
)
Serial No.:	09/882,480) Art Unit
) 2814
Filed:	June 14, 2001)
)
Confirmation No.:	8120)
)
For:	HIGH DENSITY SINGLE TRANSISTOR)
	FERROELECTRIC NON-VOLATILE MEMORY)
)
Examiner:	Marcos D. Pizarro-Crespo)

PRELIMINARY AMENDMENT

Mail Stop: RCE
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

This communication is in response to Examiner's Office Action mailed November 16, 2004 (the "Office Action"). Reconsideration is respectfully requested in view of the following amendments and remarks.

Amendments to the Claims are reflected in the listing of claims that begins on page 2 of this paper.

Remarks/Arguments begin on page 17 of this paper.